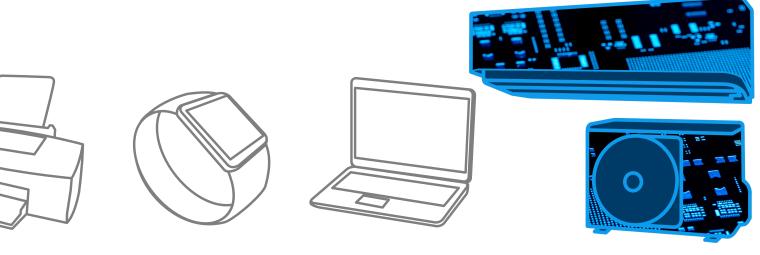
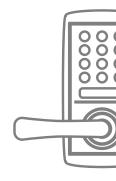
Air Conditioner

Solution Proposal by Toshiba



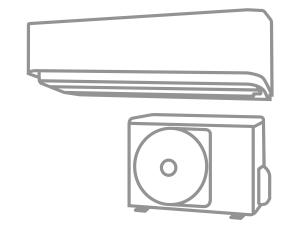




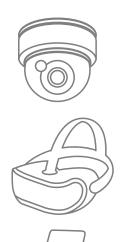






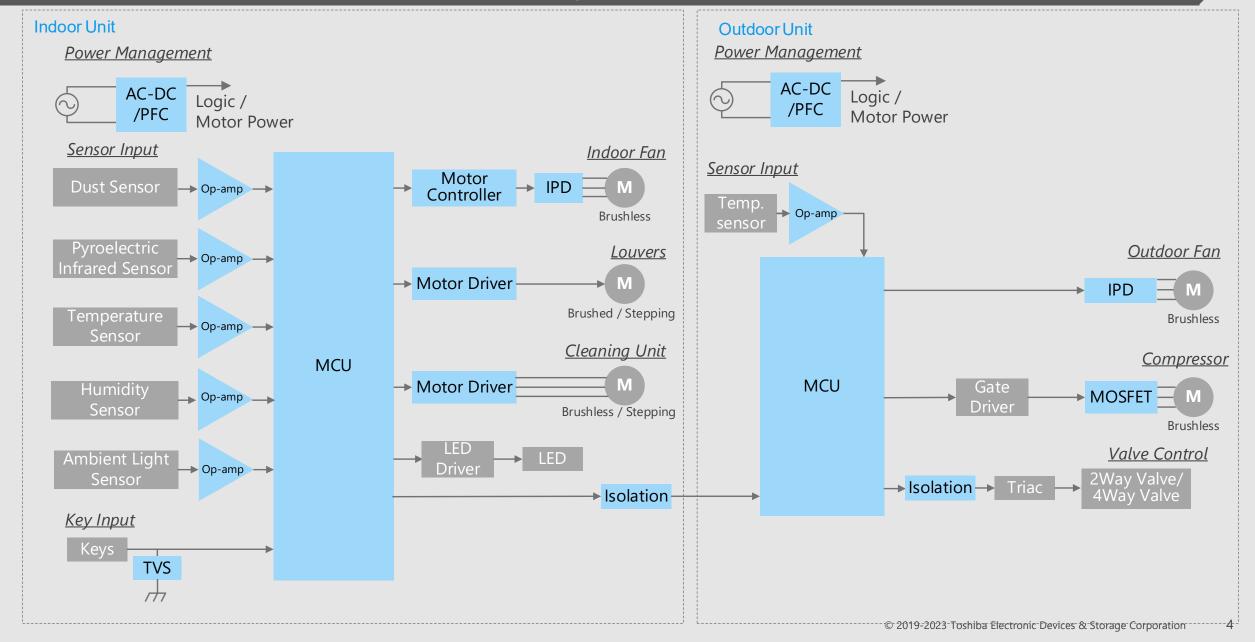


Toshiba Electronic Devices & Storage Corporation provides comprehensive device solutions to customers developing new products by applying its thorough understanding of the systems acquired through the analysis of basic product designs.



Block Diagram

Air Conditioner Overall Block Diagram



Air Conditioner Details of AC-DC converter unit

Outdoor unit Outdoor unit Driver Photo Controller Photo Coupler Reference

AC-DC converter circuit

Indoor unit

12 V

5 V

N-ch

MOSFET

PWM
Photo
Controller

Controller

Reference

Criteria for device selection

- High voltage MOSFETs are suitable for primary switching of AC-DC converters.
- The transistor output photocoupler is for signal isolation.

Proposals from Toshiba

- Suitable for high efficiency voltage switching π-MOSWI Series MOSFET
- High current transfer ratio and high temperature operation have been achieved Transistor output photocoupler
- Supply the power with low noise
 Small surface mount LDO regulator



^{*} Click on the numbers in the circuit diagram to jump to the detailed descriptions page

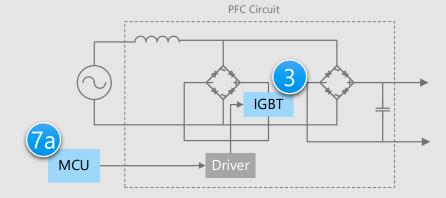
Air Conditioner Details of PFC unit

MCU

PFC circuit Active type To priver

PFC circuit

Partial switching type



Controller

Criteria for device selection

- MOSFETs with high speed switching and low on-resistance are suitable for active type PFC circuit.
- IGBTs with low collector-emitter saturation voltage are suitable for partial switching type
 PFC circuit.

Proposals from Toshiba

Suitable for high efficiency power supply switching

DTMOSVI Series MOSFET

 IGBT which is suitable for high voltage and high current system

Discrete IGBT

Suitable for PFC and motor control

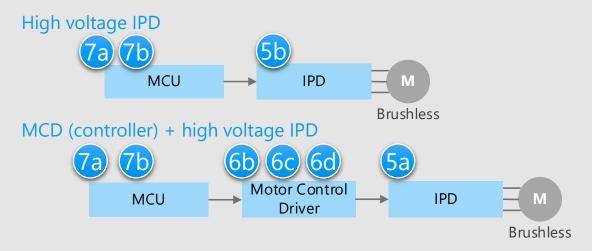
MCU M4K Group / M470 Group / M370 Group

3

* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Air Conditioner Details of fan (indoor/outdoor) and compressor unit

Fan section (indoor/outdoor units)



MCU (Three-phase motor controller) + high voltage IPD



Compressor section



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Criteria for device selection

- IPDs are suitable for fan motor drive in indoor and outdoor units.
- MOSFET with short reverse recovery time is suitable for motor drive in compressors.
- By using brushless motor drivers, three-phase brushless DC motors can be controlled easily.

Proposals from Toshiba

Suitable for inverter
 DTMOSIV (HSD) [Note] Series MOSFET



High voltage motor driver circuit
 High voltage IPD



Easy motor drive
 Motor driver



Suitable for PFC and motor control
 MCU M4K Group / M470 Group / M370 Group



 Easy software development using general purpose CPU cores

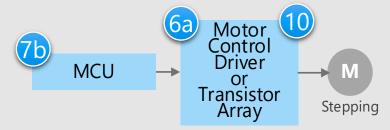




[Note] 4th generation DTMOS with high speed diode

Details of cleaning, louver and valve control unit Air Conditioner

Cleaning section

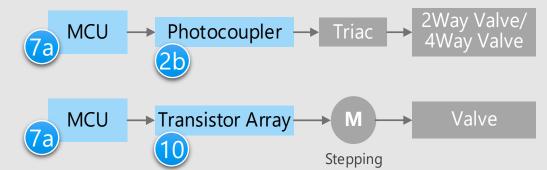


Louver section



Stepping or Brushed

Valve control section



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Criteria for device selection

- By using brushless DC motor drivers, threephase brushless DC motors can be controlled easily.
- Stepping motor driver enables efficient motor control by optimizing real-time current to the motor.
- Brushed DC motor driver allows motor driving with low power consumption.

Proposals from Toshiba

Easy motor drive Motor driver

Triac driver for high dv/dt

Triac output photocoupler

Suitable for PFC and motor control MCU M4K Group / M470 Group / M370 Group

Easy software development using general purpose CPU cores

MCU M3H Group

High efficiency and high current driver wi **built-in low loss DMOS FET** Transistor array







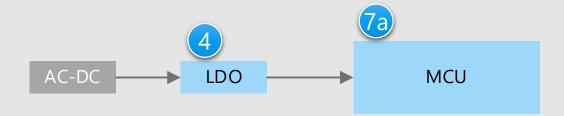




Air Conditioner Details of microcontroller and isolation unit

Microcontroller section

Power control block for outdoor unit



Isolation circuit

Between outdoor and indoor units



Criteria for device selection

- Isolation devices such as transistor output photocouplers are effective when voltage difference exists between outdoor and indoor GNDs
- MCUs are suitable for system monitoring and control.

Proposals from Toshiba

- High current transfer ratio and high temperature operation have been achieved Transistor output photocoupler
- Supply the power with low noise Small surface mount LDO regulator
- Suitable for PFC and motor control MCU M4K Group / M470 Group / M370 Group
- Easy software development using genera purpose CPU cores
 MCU M3H Group

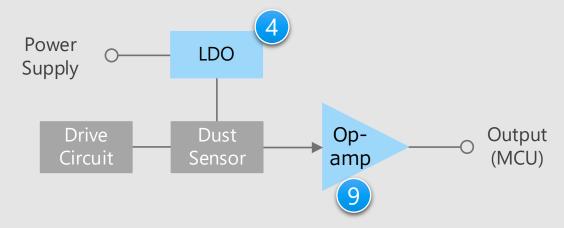




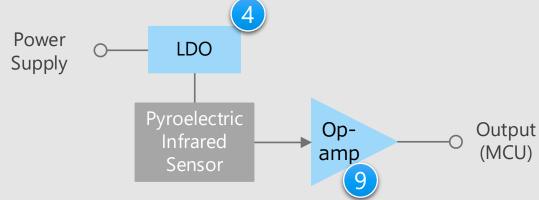
* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Air Conditioner Details of sensor input unit (1)

Dust sensor circuit



Human sensor circuit



Criteria for device selection

- PSRR (Power Supply Rejection Ratio) of LDO regulator is an important parameter for sensor modules.
- The operational amplifier should be low current consumption or low noise device.
- Small package products contribute to the reduction of circuit board area.

Proposals from Toshiba

Supply the power with low noise
 Small surface mount LDO regulator



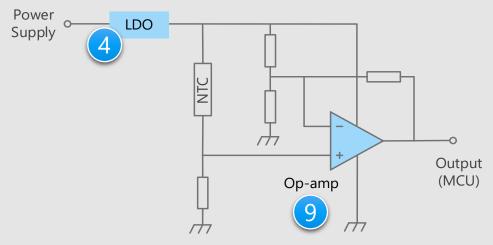
- Amplification of detected very small signal with low noise
 - Low current consumption op-amp
 / Low noise op-amp



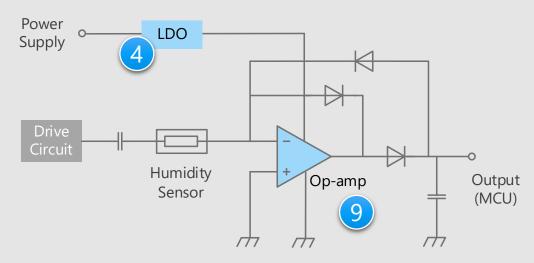
^{*} Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Air Conditioner Details of sensor input unit (2)

Temperature sensor circuit



Humidity sensor circuit



Criteria for device selection

- PSRR (Power Supply Rejection Ratio) of LDO regulator is an important parameter for sensor modules.
- The operational amplifier should be low current consumption or low noise device.
- Small package products contribute to the reduction of circuit board area.

Proposals from Toshiba

Supply the power with low noise
 Small surface mount LDO regulator



- Amplification of detected very small signal with low noise

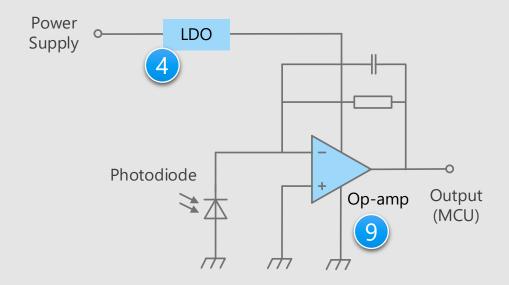
Low current consumption op-amp / Low noise op-amp



^{*} Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Air Conditioner Details of sensor input unit (3)

Ambient light sensor circuit



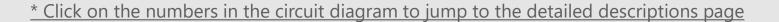
Criteria for device selection

- PSRR (Power Supply Rejection Ratio) of LDO regulator is an important parameter for sensor modules.
- The operational amplifier should be low current consumption or low noise device.
- Small package products contribute to the reduction of circuit board area.

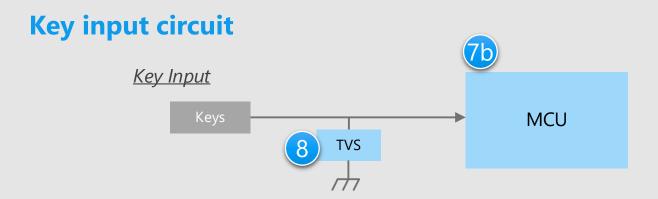
Proposals from Toshiba

- Supply the power with low noise
 Small surface mount LDO regulator
- Amplification of detected very small signal with low noise
 - Low current consumption op-amp / Low noise op-amp





Air Conditioner Detail of key input unit



Criteria for device selection

- TVS diodes are suitable for protection from ESD pulses coming in key input unit.
- Small package products contribute to the reduction of circuit board area.

Proposals from Toshiba

- Easy software development using general purpose CPU cores
MCU M3H Group



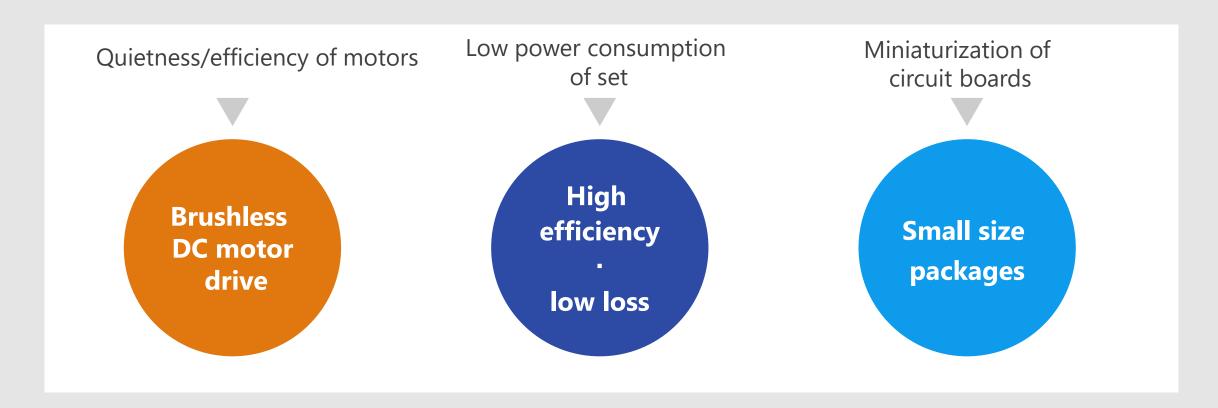
 Absorb static electricity to prevent malfunction of the circuit TVS diode





Device solutions to address customer needs

As described above, in the design of air conditioner, "Quietness/efficiency of motors", "Low power consumption of set" and "Miniaturization of circuit boards" are important factors. Toshiba's proposals are based on these three solution perspectives.



Device solutions to address customer needs

		Brushless DC motor drive	High efficiency . low loss	Small size packages	
1	$\pi\text{-MOSW}$ / DTMOSVI / DTMOSIV (HSD) Series MOSFET				
2	Transistor output photocoupler / Triac output photocoupler				
3	Discrete IGBT				
4	Small surface mount LDO regulator				
5	High voltage IPD				
6	Motor driver				
7	MCU M4K Group / M470 Group / M370 Group / M3H Group				
8	TVS diode				
9	Low current consumption op-amp / Low noise op-amp				
10	Transistor array				







Realizes improvement of power supply efficiency by reduction of RonA by 24 % (comparison of Toshiba's conventional products) and contributes miniaturization of set.

RonA reduced by 24 %

By using π -MOSVIII chip design, figure of merit RonA is reduced by 24 % (comparison of Toshiba's π -MOSIV products).

Q_g reduced by 23 %

By using π -MOSVIII chip design, Q_g is reduced by 23 % (comparison of Toshiba's π -MOSIV products).

Reduction of switching loss is expected.

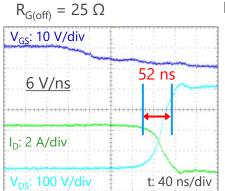
3 Coss reduced by 18 %

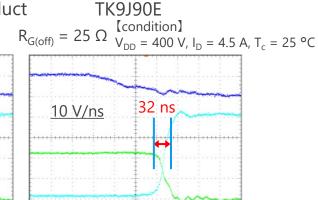
By using π -MOSVIII chip design, C_{OSS} is reduced by 18 % (comparison of Toshiba's π -MOSIV products).

Improvement for light load conditions is expected.

Turn-off waveform

Toshiba's conventional product





Lineup				
Part numb	er	TK6A80E	TK10A80E	TK9J90E
Package		TO-220SIS		TO-3P(N)
V _{DSS} [V]		800	800	900
I _D [A]	I _D [A]		10	9
$R_{DS(ON)}[\Omega]$	Тур.	1.35	0.7	1
$R_{DS(ON)} [\Omega]$ $@V_{GS} = 10 \text{ V}$	Max	1.7	1	1.3
Polarity		N-ch	N-ch	N-ch

(Note) Toshiba internal comparison



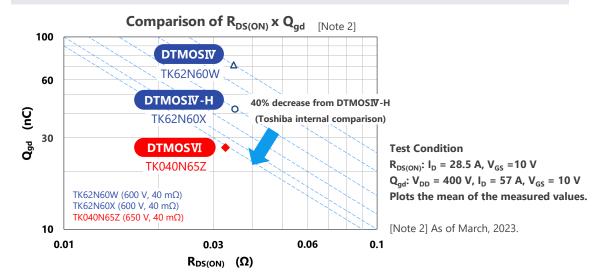




Realizes improvement of power supply efficiency by 40 % reduction of $R_{DS(ON)}$ x Q_{gd} (comparison of Toshiba's conventional products).

R_{DS(ON)} x Q_{gd} reduced by 40 %

Using a single epitaxial process, the figure of merit $R_{DS(ON)}$ x Q_{gd} was reduced by 40 % by optimizing the structure (comparison of Toshiba's DTMOSIV-H 600 V products). By realizing low $R_{DS(ON)}$ x Q_{gd} , device switching loss was reduced contributing to improvement in power supply efficiency of equipment.



RonA reduced by 18 %

The figure of merit RonA of the latest generation [Note1] DTMOSVI has been reduced by 18 % compared with the previous generation (Toshiba's DTMOSIV 650 V products). Achieving low on-resistance while maintaining high voltage contributes to high efficiency of equipment.

[Note1] As of March 2023

Lineup					
Part number		TK065U65Z	TK040N65Z		
Package		TOLL	TO-247		
V _{DSS} [V]	V _{DSS} [V]		650		
I _D [A]	I _D [A]		57		
$R_{DS(ON)}[\Omega]$	Тур.	0.051	0.033		
$\begin{array}{c} R_{DS(ON)} [\Omega] \\ @V_{GS} = 10 \text{ V} \end{array}$	Max	0.065	0.040		
Polarity		N-ch	N-ch		







The figure of merit RonA has been reduced by 30 % (compared with Toshiba conventional products), then contribute to improve efficiency of power supply.

RonA 30 % reduction

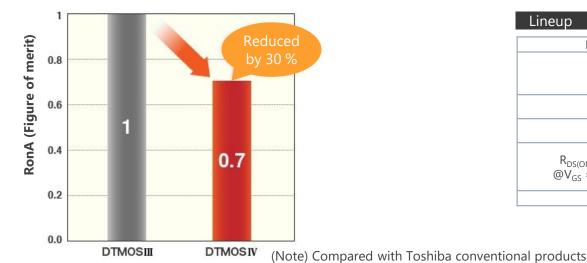
Adoption of newly developed single epitaxial process to reduce the figure of merit RonA by 30 %. (Compared with Toshiba DTMOSIII products)

2 Reduction of on-resistance increase at high temperature

The single epitaxial process reduces the on-resistance increase at high temperature.

Optimization of switching speed

Optimization of switching speed has been achieved by reduction of C_{OSS} (by 12 %, compared with Toshiba conventional products) and other factors.



Lineup					
Part number		TK20A60W5			
Package		TO-220SIS			
V _{DSS} [V]		600			
I _D [A]		20			
$R_{DS(ON)}[\Omega]$	Тур.	0.15			
$R_{DS(ON)} [\Omega]$ $@V_{GS} = 10 \text{ V}$	Max	0.175			
Polarity	•	N-ch			

◆ Return to Block Diagram TOP

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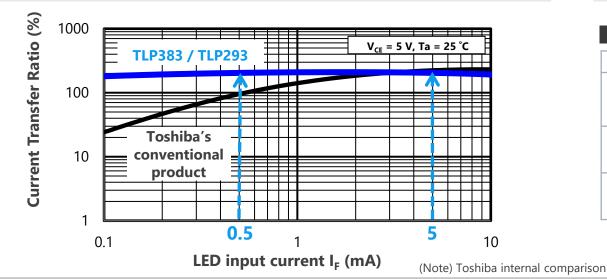




High CTR (Current Transfer Ratio) is realized even in low input current range ($I_F = 0.5 \text{ mA}$).

High current transfer ratio

The TLP383 and TLP293 is a high isolation photocoupler that optically couples a phototransistor and high output infrared LED. Compared to Toshiba's conventional products (TLP385), higher CTR (Current Transfer Ratio) in low input current range (@ I_F = 0.5 mA) is realized.



High temperature operation

The TLP383 and TLP293 are designed to operate even under severe ambient temperature conditions.

Lineup						
Part number	TLP383	TLP293	TLP385			
Package	Package 4pin SO6L		4pin SO6L			
BV _S [Vrms]	BV _s [Vrms] 5000		5000			
T _{opr} [°C]	-55 to 125	-55 to 125	-55 to 110			





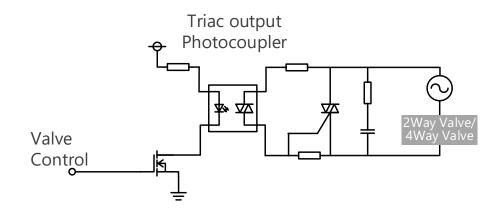


Using a triac with high dv/dt pre-driver for solenoid valve control suppresses false turn-on.

Low input and zero crossing input control

This device optically couples a photo triac and a high power infrared LED, providing high isolation equivalent to an electromagnetic relay. Capable of low input operation, the photo coupler can be directly controlled by a microcontroller.

■ Example of AC switch using triac output photocoupler



High dv/dt

The TLP3083 is a triac having a high dv/dt of 2000 V/ μ s (Typ.). With a high OFF-state voltage of 800 V, it can work with various AC power supplies.

Lineup					
Part number	TLP3083	TLP3073			
Package	5pin DIP6				
Output type	Zero crossing functionary (ZC) Non zero crossing functionary (
BV _s [Vrms]	5000				
T _{opr} [°C]	-40 to 100				







Switching devices for high voltage (600 V or more) and high current (30 A or more) application. Lineup of low $V_{CE(sat)}$ products are effective in reducing conduction loss.

High speed, low saturation voltage

By adopting a thin wafer punch-through structure, high speed turn-off characteristics and low $V_{\text{CE(sat)}}$ characteristics are realized.

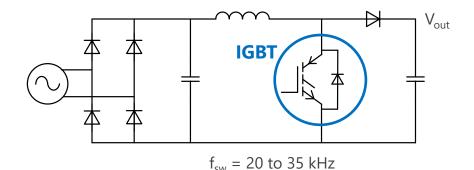
High breakdown tolerance

Toshiba has a lineup of products with high breakdown tolerance (short circuit withstand time t_{sc} and reverse bias safe operating area RBSOA).

3 Enhancement type

Since collector current does not flow when gate voltage is not applied for enhancement devices, handling is easy.

■ Active type PFC circuit example using discrete IGBT (GT50JR22)



Lineup						
Part numb	er	GT50JR22	GT30J122A	GT50J123	GT30J65MRB	
Package		TO-3P(N)				
Built-in FW	D	√ (RC structure)	-	-	√ (RC structure)	
V _{CES} [V]		600	600	600	650	
I _C [A]		50	30	59	60	
V _{CE(sat)} [V]	Тур.	1.55	1.7	1.90	1.40 @I _C = 30 A	
$V_{CE(sat)}[V]$ @I _C = 50 A, V _{GE} = 15 V, T _a = 25 °C	Max	2.20	2.8	2.50	1.80 @I _C = 30 A	
Breakdown	t _{sc} [μs]	-	-	5	-	
tolerance	RBSOA	-	-	120 A, 600 V (full square)	-	







Wide lineup from general purpose type to small package type are provided. Contribute to realize a stable power supply not affected by fluctuation of battery.

Low dropout voltage

The originally developed latest process significantly improved the dropout voltage characteristics.

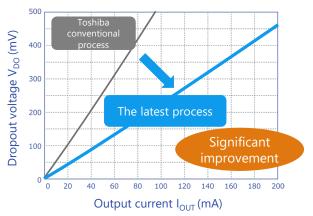
High PSRR Low output noise voltage

Many product series that realize both high PSRR (Power Supply Rejection Ratio) and low output noise voltage characteristics are provided. They are suitable for stable power supply for analog circuit.

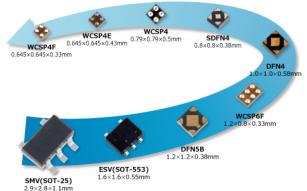
3 Low current consumption

 $0.34~\mu A$ of $I_{B(ON)}$ is realized by utilizing CMOS process and unique circuit technology. (TCR3U Series)

Low dropout voltage



Rich package lineup



Lineup									
Part number	TCR15AG Series	TCR13AG Series	TCR8BM Series	TCR5BM Series	TCR5RG Series	TCR3RM Series	TCR3U Series	TCR2L Series	TAR5 Series
Features	Low dropout voltage High PSRR			Low Low c	PSRR noise urrent mption		urrent mption	15 V Input voltage Bipolar type	
I _{OUT} (Max) [A]	1.5 1.3 0.8 0		.5	0	.3		0.2		
PSRR (Typ.) [dB] @f = 1 kHz	95	90	98	98	100	100	70	-	70
I _B (Typ.) [μΑ]	25	56	20	19	7	7	0.34	1	170

◆ Return to Block Diagram TOP

(Note) Toshiba internal comparison with TCR3U series.







It is a brushless DC motor driver with built-in MOSFETs or IGBTs and can be driven at a variable speed by control signals from the MCU.

Built-in circuit required to drive the motor

It contains a level shifting high side driver, low side driver and MOSFETs or IGBTs.

TPD4204F: MOSFET output

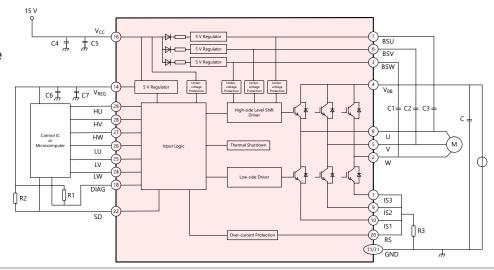
TPD4163F/TPD4163K/TPD4164F/TPD4164K: IGBT

Motor drive terminals and control terminals are separated

High voltage and large current terminals and the control terminals are separated on both sides of the package, thereby eliminating the complexity of wiring. **3** Various protection functions

Over current and under voltage protection, shutdown and thermal shutdown functions are available.

TPD4163F Application Circuit Example



output

Lineup					
Part number	TPD4204F	TPD4163F	TPD4164F	TPD4163K	TPD4164K
Package	P-SSOP30-1120-1.00-001	P-HSSOP31-0	918-0.80-002	P-HDIP30-12	233-1.78-001
V _{BB} [V]	600				
I _{out} [A]	2.5	1.0	2.0	1.0	2.0
V _{CC} [V]	13.5 to 16.5				







This product optimizes for brushless DC motor driving and has the functions required for motor driving into one package.

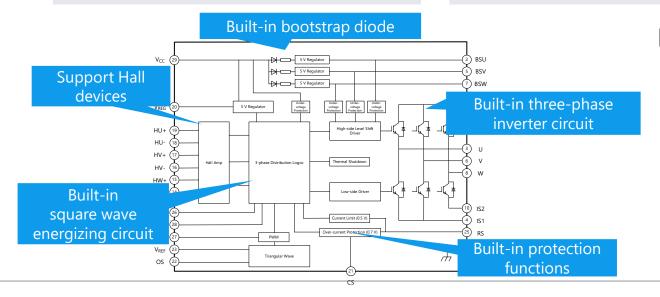
Contributing to low power consumption

The power consumption can be reduced by replacing from the AC motor to a brushless DC motor.

Contributing to reducing the number of parts

Built-in functions and protection functions required for inverter operation can reduce the number of parts. **Solution** Contributing to reduction of circuit board area

The use of small surface mount packages contributes to the reduction of circuit board area.



Lineup						
Part number	TPD4162F					
Package	P-HSSOP31-0918-0.80-002					
V _{BB} [V]	600					
I _{out} [A]	0.7					
V _{CC} (Max) [V]	17.5					
Protective function	Current limitation, overcurrent protection, thermal shutdown, under voltage protection					







Support low voltage motor drive (2.5 V (Min)) and contributes to the power saving of set.

Low voltage operation

Motor power supply voltage is 2.5 V (Min) for low voltage applications such as battery operation devices.

2 Low current consumption

Standby current is 2 μ A or less (IC total) for power saving of devices.

3 Error detection functions

Over current detection (ISD), thermal shutdown (TSD) and under voltage lockout (UVLO) are available.



P-TSSOP16-0505-0.65-001 Package (5.0 x 6.4 x 1.2 mm)



P-VQFN16-0303-0.50-001 Package (3.0 x 3.0 x 0.9 mm)

Lineup			
Part number	TC78H621FNG	TC78H660FNG	TC78H660FTG
V _M [V]	18	18	18
I _{OUT} [A]	1.1	2.0	2.0
$R_{on (upper and lower sum)} (Typ.) [\Omega]$	0.8	0.48	0.48
Control interface	PHASE input	IN/PHASE inputs	IN/PHASE inputs
Step	2phase/1-2phase excitation	2phase/1-2phase excitation	2phase/1-2phase excitation
Motor power supply voltage	2.5 V (Min)	2.5 V (Min) RS resister less	2.5 V (Min) RS resister less
Error detection function	ISD, TSD, UVLO	ISD, TSD, UVLO	ISD, TSD, UVLO
Package	P-TSSOP16-0505-0.65-001	P-TSSOP16-0505-0.65-001	P-VQFN16-0303-0.50-001







Toshiba's proprietary technology eliminates the need for phase adjustment and achieves high efficiency for a wide range of rotation speeds.

High efficiency in a wide range of rotation speeds

Toshiba's automatic lead angle control technology realizes a high efficiency drive regardless of motor speed, load torque or power supply voltage.

Motor control with low noise and low vibration

Sine wave drive system with smooth current waveforms contributes to lower motor noise and vibration compared to conventional square wave drive system [Note].

3 Small package

VQFN32 package is adopted for TC78B042FTG, which requires small space. SSOP30 package is adopted for TC78B041FNG as conventional type.

[Note] Comparison with Toshiba products



SSOP30-P-300-0.65 Package (10.2 x 7.6 x 1.6 mm)



P-VQFN32-0505-0.50-005 Package (5 x 5 x 1 mm)

Lineup					
Part number	TC78B041FNG	TC78B042FTG			
Power supply voltage	6 to 16.5 V (op	perating range)			
Drive type	Sine wa	ve drive			
	Auto lead angle control for optin	nizing voltage and current phases			
	Hall element or hall IC input				
	Forward/reverse rotation switch				
Features	Motor lock detection				
	Selectable pulse number of rotation pulse signal output				
	Built-in 5 V regulator (VREF pin)	Built-in 5 V regulators (VREF/VREF2 pin)			
	Error detection positive input	Error detection positive/negative input			
Package	SSOP30-P-300-0.65	P-VQFN32-0505-0.50-005			







High voltage and high current brushless DC motor driving can be implemented by external IPD.

High efficient motor control by automatic phase control

Automatic phase controller by current feedback is integrated adding conventional fixed phase voltage input (32 steps).

Motor control with low noise and low vibration

Sine wave drive system with smooth current waveforms contributes to lower motor noise and vibration compared to conventional square wave drive system [Note].

Sufficient development support

Various supports such as third party evaluation board and PSpice® data for development and design are prepared.

[Note] Comparison with Toshiba products

TB6584FNG, TB6584AFNG TB6634FNG



SSOP30-P-300-0.65 Package (10.2 x 7.6 x 1.6 mm)

Lineup			
Part number	TB6584FNG	TB6584AFNG	TB6634FNG
Supply voltage	6	to 16.5 V (operating rang	je)
Output current	0.002 A (for MOSFET driver)		
Drive mode	Sine wave drive		
Features	Lead angle control: Auto phase control (current feedback) Sensor input: Hall device/Hall IC compatible Internal regulator: 5 V, 30 mA (Max) Error detection: overcurrent protection, abnormal position signal protection undervoltage lockout, motor restrained detection (TB6634FNG)		







A motor control IC and IGBTs are integrated into one package, contributing to the miniaturization of circuit boards.

A motor control IC and IGBTs

A motor control IC with sine wave PWM drive function and IGBTs with 600 V and 2 A characteristics are integrated into one package.

Motor control with low noise and low vibration

Sine wave drive system with smooth current waveforms contributes to lower motor noise and vibration compared to conventional square wave drive system [Note].

3 High heat dissipation

HDIP30 package is adopted for TB67B000AHG, which has high heat dissipation. HSSOP34 package is adopted for TB67B000AFG, which is smaller than HDIP30.

[Note] Comparison with Toshiba products



P-HDIP30-1233-1.78-001 (32.8 x 13.5 x 3.525 mm)



P-HSSOP34-0918-0.80-001 (17.5 x 11.93 x 2.2 mm)

Lineup				
Part number	TB67B000AHG TB67B000AFG			
Operating voltage range	Power supply for control: 13.5 to 16.5 V			
Operating voltage range	Power supply for motor drive: 50 to 450 V			
Output current	2 A			
Drive type	Sine wave PWM drive / Wide angle commutation			
Lead angle control	0 to 58 degrees 32 steps / 0 to 28 degrees 16 steps			
Speed command input voltage	e Motor operation: 2.1 to 5.4 V			
Features	IGBT three-phase bridge, oscillator circuit, built-in bootstrap diode, overcurrent protection, thermal shutdown, undervoltage lockout, motor lock detection			
Package	P-HDIP30-1233-1.78-001 P-HSSOP34-0918-0.80-001			







System cost reduction, higher efficiency and less development work.

Equipped with motor control co-processor

Toshiba's original co-processor vector engine (VE) for motor control reduces CPU load and allows control of multiple motors and peripherals.

2 Equipped with motor control circuit

A variety of three-phase PWM [Note 1] waveforms and AD converters enable highly efficient, low noise control. The Advanced Encoder (A-ENC) reduces the load of CPU process in detecting the position performed for each PWM.

Provide development support tools

Third party evaluation boards and sample programs that can be used to shorten the development time are provided. Toshiba has begun offering a new, simple, versatile motor control software development kit (MCU Motor Studio). [Note 2]

[Note 1] Pulse Width Modulation

[Note 2] For M4K Group and will gradually expand for TXZ+TM Series products

ROM size						[Note 1]	Pulse Width Modulation
512 KB							
384 KB							
256 KB							M4K Group
128 KB							M470 Group
64 KB							M370 Group
	30	44	48	64	80	100	pins

Lineup		
Series	Group	Function
TXZ+ TM 4A Series	M4K Group	Arm® Cortex®-M4, 160 MHz operation 4.5 to 5.5 V, three motor control (Max), Data Flash
TX04 Series	M470 Group	Arm® Cortex®-M4, 120 MHz operation 4.5 to 5.5 V, two motor control (Max)
TX03 Series	M370 Group	Arm® Cortex®-M3, 80 MHz operation 4.5 to 5.5 V, two motor control (Max)







MCU is equipped with many peripheral functions. MCU contributes to higher functionality as a system control MCU.

Built-in Arm® Cortex®-M3
CPU core

MCU is equipped with Arm Cortex-M3 core. Maximum operation frequency is 120 MHz.

Various lineup of built-in memories and packages

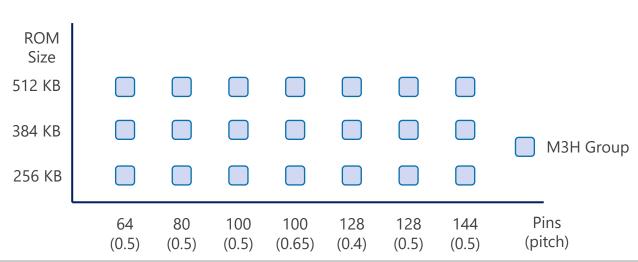
M3H group integrates both 512 KB (Max) code and 32 KB data flash memories which support 100,000 write cycle endurance, and has a wide lineup of package from 64 to 144 pins.

Solution Equipped with many peripheral functions

M3H Group have many peripheral functions such as UART, SPI, I²C, 12bit AD converter, 8bit DA converter, three-phase PWM [Note1] output, ENC and digital LCD driver [Note2], etc.

[Note 1] Pulse Width Modulation

[Note2] 64 pin products aren't equipped with digital LCD driver.



Lineup		
Series	Group	Function
TXZ+ TM 3A Series	M3H Group	Arm® Cortex®-M3, 120 MHz, 2.7 to 5.5 V operation







Absorbs static electricity from external terminals, prevents circuit malfunction and protects devices.

High ESD pulse absorption performance

Improved ESD absorption compared to Toshiba's conventional products. (50 % reduction in operating resistance) For some products, both low operating resistance and low capacitance are realized and ensures high signal protection performance and signal quality.

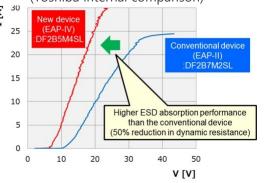
Suppress ESD energy by low clamp voltage

Protect the connected circuits and devices using Toshiba own technology.

Suitable for high density mounting

A variety of small packages are available.

ESD Pulse Absorption Performance (Toshiba internal comparison)



Unidirectional



Suitable for paths such as logic signals. There are lineups of 1in1, 2in1, 4in1, 5in1, 7in1.

Bidirectional



Suitable for paths with both polar signals such as audio signals

Lineup					
Part number	DF2B7BSL	DF2B5M4SL	DF2B6M4SL		
Package	SL2	SL2	SL2		
V _{ESD} [kV]	±30	±20	±20		
V _{RWM} (Max) [V]	5.5	3.6	5.5		
C _t (Typ.) [pF]	12	0.2	0.2		
R _{DYN} (Typ.) [Ω]	0.2	0.5	0.5		

(Note) This product is an ESD protection diode and cannot be used for purposes other than ESD protection.

Low current consumption op-amp / Low noise op-amp tc755102F / Tc75567TU







Value provided

Lineup includes low current consumption type that contributes to low power consumption and a low noise type that maximizes the performance of high performance sensors.

Low voltage operation

We have a lineup of low power supply voltage-driven operational amplifiers using CMOS process for low power supply voltage-driven wearable equipment.

Low current consumption
(TC75S102F) I_{DD} = 0.27 [μA] (Typ.)

CMOS processes have been used to achieve lower current consumption. This contributes to lower power consumption and longer life of wearable equipment.

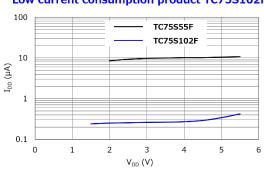
Low noise (TC75S67TU)V_{NI} = 6.0 [nV/√Hz] (Typ.) @f = 1 kHz

This CMOS operational amplifier can amplify minute signals detected by various sensors [Note] with low noises. By optimizing the process, the equivalent input noise voltage has been reduced.

TC75S102F

Current Consumption Characteristic (Toshiba internal comparison)

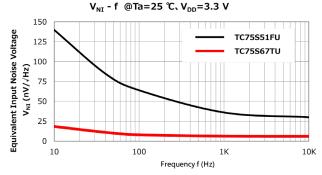
Low current consumption product TC75S102F



TC75S67TU

Noise Characteristic (Toshiba internal comparison)

Reduce 1/f noise (10 Hz) by 86 % from our normal products



[Note] Sensor types: vibration, shock, acceleration, pressure, infrared, temperature, etc.

Lineup					
Part number	TC75S102F	TC75S67TU			
Package	Package SMV				
V _{DD} - V _{SS} [V]	1.5 to 5.5	2.2 to 5.5			
V _{IO} (Max) [mV]	1.3	3			
CMV _{IN} (Max) [V]	V_{DD}	1.4 (@V _{DD} = 2.5 V)			
I _{DD} (Typ. / Max) [μΑ]	0.27 / 0.46 (@V _{DD} = 1.5 V)	430 / 700 (@V _{DD} = 2.5 V)			
V _{NI} (Typ.) [nV/√Hz] @f = 1 kHz	-	6			







DMOS FET is used for the output of drive circuit and realizes low loss. And CMOS input can control directly from controller's I/O, etc.

Rich product lineup

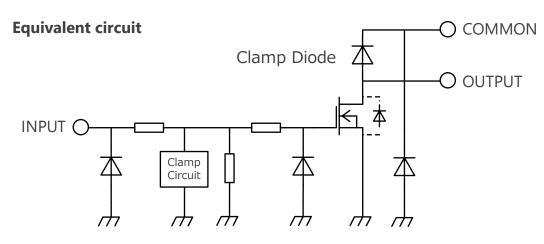
In addition to the listed products, we have lineup of various packaged products (such as DIP, SOL, SOP, SSOP, etc.) and source output type products.

Built-in output clamp diode

Built-in output clamp diode regenerates the back electromotive force generated by switching of an inductive.

Higher current drive is possible

The load can be driven with higher current by connecting multiple outputs in parallel.



Lineup			
Part number	TBD62003AFWG	TBD62083AFG	TBD62064AFAG
Package	P-SOP16-0410-1.27-002	SOP18-P-375-1.27	P-SSOP24-0613-1.00-001
Output type	Sink	Sink	Sink
Number of channels	7ch	8ch	4ch
Input level	Н	Н	Н
I _{OUT} [mA/ch]	500	500	1500
V _{OUT} [V]	50	50	50

(Note) Equivalent circuit may be simplified for explanatory purpose.

If you are interested in these products and have questions or comments about any of them, please do not hesitate to contact us below:

Contact address: https://toshiba.semicon-storage.com/ap-en/contact.html

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